



MT 1
 MT 2
 GATE

SYM.	INCHES		
A	0.410	0.430	
В	0.097	0.103	
С	1.160	1.175	
D	0.340	0.350	
E	0.375	0.475	
F	0.085	0.200	
G	0.090	0.160	
H	0.030	0.035	
J	0.045	0.055	
K	0.070	0.080	
L	0.019	0.025	
M	0.175	0.195	
N	0.190	0.210	

Maximum Ratings	Symbol	Value	Unit
REPETITIVE PEAK OFF-STATE VOLTAGE (1)GATE OPEN, AND TJ=110°C/VDRM		800	Volt
RMS ON-STATE CURRENT AT TC = 80° C AND CONDUCTION, ANGLE OF 360°	IT(RMS)	15.0	Amp
PEAK SURGE (NON-REPETITIVE) ON-STATE CURRENT, ONE-CYCLE, AT 50HZ OR 60HZ	ITSM	150	Amp
PEAK GATE - TRIGGER CURRENT FOR 3µSEC. MAX.	IGTM	4	Amp
PEAK GATE-POWER DISSIPATION AT IGT≤IGTM	PGM	40	Watt
AVERAGE GATE - POWER DISSIPATION	PG(AV)	0.8	Watt
STORAGE TEMPERATURE RANGE	TSTG	-40 to +150	°C
OPERATING TEMPERATURE RANGE, TJ	TOPER	-40 to +110	°C
PEAK OFF - STATE CURRENT (1) GATE OPEN TC = 110° C VDRM = MAX. RATING	IDRM	0.5	MA Max.
MAXIMUM ON - STATE VOLTAGE, (1) AT TC = 25° C AND IT = RATED AMPS	VTM	2.2	Volt Max.
DC HOLDING CURRENT, (1) GATE OPEN AND TC = 25° C	IHO	50	MA Max.
CRITICAL RATE-OF-RISE OF OFF-STATE VOLTAGE, (1) FOR VD =VDRM GATE OPEN, TC = 110° C	Critical dv/dt	150	V/μSEC.
CRITICAL RATE-OF-RISE OF COMMUTATING VOLTAGE, (1) AT TC = 80° C, GATE ENENERGIZED, VD=VDRM IT=IT (RMS)	COMMUTATING dv/dt	4	V/μSEC.
DC GATE - TRIGGER CURRENT FOR VD = 12VDC. RL = 60 ohm AND AT TC = 25° C (T2 + GATE + T2 - GATE-) QUADS I & III (T2 + GATE - T2 - GATE +) QUADS II & IV	IGT	50 I, III 80 II, IV	MA Max.
DC GATE - TRIGGER VOLTAGE FOR VD = 12VDC. RL = 60 ohm AND AT TC = 25° C	VGT	2.5	Volt Max.
GATE CONTROLLED TURN-ON TIME FOR VD = VDRM IGT = 80MA TR = 0.1 μ SEC. IT = 10A (PEAK) AND TC = 25° C	TGT	2.5	μSEC.
THERMAL RESISTANCE, JUNCTION-TO-CASE	R <i>θ</i> J-C	2.5	°C/Watt Typ.

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